



60V NPN MEDIUM POWER TRANSISTOR IN SOT23

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirement of Automotive Applications.

Features

- BV_{CEO} > 60V
- Maximum Continuous Collector Current I_C = 5A
- V_{CE(SAT)} < 45mV @ 1A
- $R_{CE(SAT)} = 25m\Omega$
- High Power Dissipation SOT23 (Type DN) Package
- High Peak Current
- Low Saturation Voltage
- 140V Forward Blocking Voltage
- Complementary Part Number ZXTP2027FQ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.008 grams (Approximate)

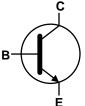
Applications

- MOSFET and IGBT Gate Driving
- Motor Drive
- Relay, Lamp and Solenoid Drive

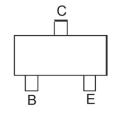




Top View



Device Symbol



Top View Pin-Out

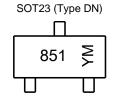
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTN2018FQTA	Automotive	851	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



851 = Product Type Marking Code YM = Date Code Marking Y = Year ex: G = 2019M = Month ex: 9 = September

Date Code Kev

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н	I	J	K	L	М	N	0	Р	Q
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		_	_	4		•		_	_		N	7

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	140	V
Collector-Emitter Voltage	V _{CEV}	140	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	5	Α
Base Current	I _B	1	Α
Peak Pulse Current	I _{CM}	12	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1.0 8.0		
Power Dissipation Linear Derating Factor	(Note 7)	P_{D}	1.2 9.6	W mW/°C	
	(Note 8)		1.56 12.5		
	(Note 6)		125		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	104	°C/W	
	(Note 8)		80		
Operating and Storage Temperature Range		T_{J}, T_{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

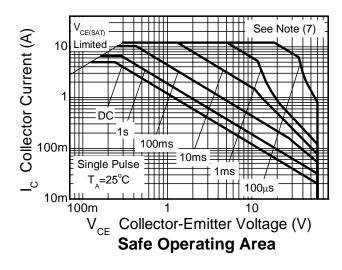
Notes:

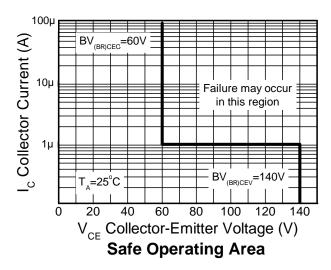
^{6.} For a device mounted with the collector lead on 18mm × 18mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady-state.

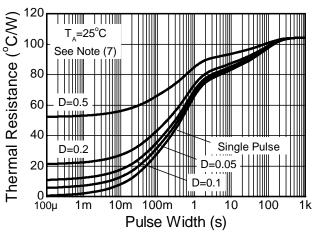
^{7.} Same as note (6), except the device is mounted on $30\text{mm} \times 30\text{mm}$ 2oz copper. 8. Same as note (6), except measured at t < 5 seconds. 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

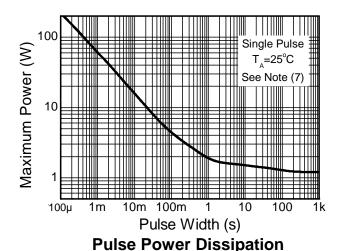


Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)









Transient Thermal Impedance

1.2 See Note (7)

1.0 See Note (6)

See Note (6)

See Note (6)

20 40 60 80 100 120 140 160

Temperature (°C) **Derating Curve**



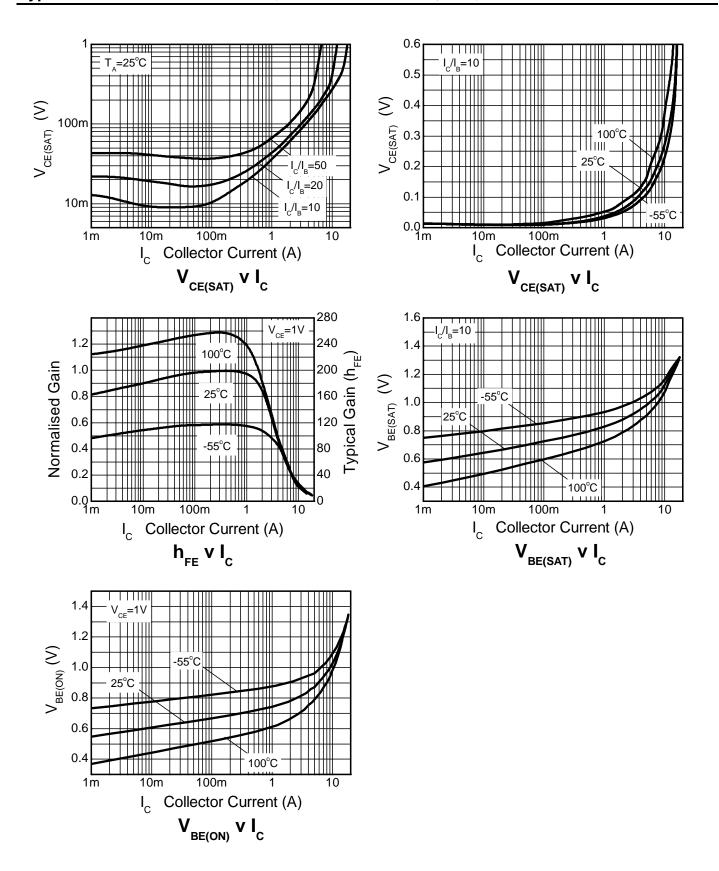
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	140	180	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage	BV _{CEV}	140	180	_	V	$I_C = 1\mu A$, $-1V < V_{BE} < +0.3V$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	60	80	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8	_	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	< 1	50	nA	V _{CB} = 110V
Collector-Emitter Cutoff Current	I _{CEV}	_	< 1	100	nA	V _{CB} = 110V, V _{BE} = -1V
Emitter-Base Cutoff Current	I _{EBO}	_	< 1	10	nA	V _{EB} = 6V
		100	220	_		$I_C = 10mA$, $V_{CE} = 1V$
Static Forward Current Transfer Datic (Note 10)	L	100	200	300	_	$I_C = 2A$, $V_{CE} = 1V$
Static Forward Current Transfer Ratio (Note 10)	h _{FE}	40	65	_		$I_C = 5A$, $V_{CE} = 1V$
		15	25	_		I _C = 10A, V _{CE} = 1V
	V _{CE} (SAT)	_	15	30		$I_C = 0.1A$, $I_B = 5mA$
		_	35	45	mV	$I_C = 1A$, $I_B = 100mA$
Collector Emitter Saturation Voltage (Note 10)		_	40	55		$I_C = 1A, I_B = 50mA$
Collector-Emitter Saturation Voltage (Note 10)		_	85	110		$I_C = 2A, I_B = 50mA$
		_	145	170		$I_C = 5A$, $I_B = 250mA$
		_	170	210		$I_C = 6A, I_B = 300mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(SAT)}	_	0.92	1.00	V	$I_C = 5A$, $I_B = 250mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(ON)}	_	0.85	0.95	V	I _C = 5A, V _{CE} = 1V
Output Capacitance	C _{OBO}	_	28	_	pF	$V_{CB} = 10V, f = 1MHz$
Transition Frequency	f_{T}	_	130	_	MHz	V _{CE} = 10V, I _C = 100mA, f = 50MHz
Turn-On Time	ton	_	33	_	ns	V _{CC} = 10V, I _C = 1A,
Turn-Off Time	toff	_	668	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

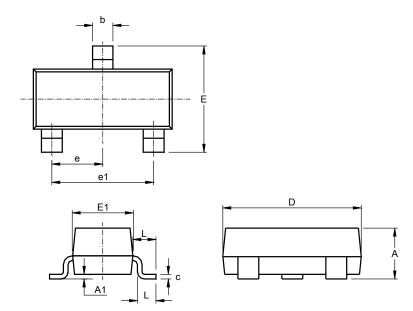




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Type DN)

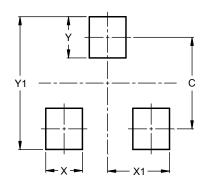


SOT23 (Type DN)						
Dim	Min	Max	Тур			
Α	0.89	1.12	1.00			
A1	0.01	0.10	0.05			
b	0.30	0.51	0.45			
С	0.08	0.20	0.10			
D	2.80	3.04	3.00			
Е	2.10	2.64	2.42			
E1	1.20	1.40	1.37			
е	0.95 REF					
e1	1.90 REF					
L	0.25	0.60	0.30			
L1	0.45	0.62	0.54			
All	Dimens	ions in	mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Type DN)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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